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Supporting Information

Preferred geometries and energies of sulfur-sulfur interactions in crystal structures

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The methanethiol structure is optimized using MP2 method and cc-pVQZ basis set. The theoretical IR spectrum is shown on Figure S1.



Figure S1. IR spectrum for optimized geometry of methanethiol molecule (monomer)

Vibrational frequencies for optimized geometry of methanethiol molecule (Table S1) have only positive values, which confirms that optimized geometries are correct.

Frequencies (cm ⁻¹)	Intensities
261.113	66.215
733.511	818.686
814.441	229.189
988.797	235.252
1106.73	581.061
1370.06	290.035
1494.27	23.886
1507.57	379.186
2757.18	227.672
3088.91	100.000
3190.49	210.989
3193.34	20.284

Table S1. Vibrational frequencies and intensities of IR spectrum of methanethiol molecule

Results of CCSD(T)/CBS calculations of interaction energy are presented in Table S2. CCSD(T)/CBS interaction energies are calculated by applying the extrapolation scheme of Makie for different orientations of two methanethiol molecules to find the minima on CCSD(T) potential curve by varying the value of normal distance (equilibrium distance) R. In the Table S2 are three sets of R values (R_1 , R_{min} and R_2); R_1 values are 0.5 Å greater than R_{min} , and R_2 values are 0.5 Å smaller than R_{min} values for all model systems. In this way, we show the equilibrium (R_{min}) distances for the minima on the CCSD(T) potential curve.

 Table S2. Calculated CCSD(T)/CBS energy values and normal distances R for all examined model systems

Model	R ₁ (Å)	E _{int} CCSD(T) (kcal/mol)	R _{min} (Å)	E _{int} CCSD(T) (kcal/mol)	$\mathbf{R}_{2}(\mathbf{\mathring{A}})$	E _{int} CCSD(T) (kcal/mol)
Α	4.0	-0.45	4.5	-0.52	5.0	-0.38
В	3.6	-0.08	4.1	-0.72	4.6	-0.60
С	3.4	-0.46	3.9	-1.80	4.4	-1.35
D	3.5	-0.11	4.0	-0.37	4.5	-0.18
Ε	3.1	0.07	3.6	-2.20	4.1	-1.82

Table S3. Refcode list of crystal structures used for statistical analysis of data obtained from the CSD.

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1.	NALCYS19	30.	BOQCUF04	59.	HORZAQ	88.	PAGYIG
2.	NALCYS20	31.	BOQCUF05	60.	HORZEU	89.	PAMVUV
3.	NALCYS21	32.	BOQCUF06	61.	HORZIY	90.	POHJON01
4.	NALCYS22	33.	BOQCUF07	62.	HORZOE	91.	PUVWIM
5.	NALCYS23	34.	BOQCUF08	63.	HUKJUT	92.	QEKXOT
6.	NALCYS24	35.	BOQCUF09	64.	ICAKEC	93.	QEKXUZ
7.	NALCYS25	36.	BOQCUF10	65.	ICAKIG	94.	QEKYAG
8.	NALCYS26	37.	BOWKOO	66.	IFUJID	95.	QEKYEK
9.	NALCYS27	38.	BOWKOO01	67.	KEXNOR	96.	QEKYIO
10.	NALCYS28	39.	BOWKOO02	68.	KUKGAZ	97.	QEKYOU
11.	VEDCOW01	40.	BOWKOO03	69.	LCYSTN04	98.	QEKYUA
12.	YOJXOM	41.	BOWKOO04	70.	LCYSTN22	99.	QEKZAH
13.	YOJXOM01	42.	BOWKOO05	71.	LCYSTN23	100.	SOMYEZ
14.	YOJXOM02	43.	BOWKOO06	72.	LCYSTN24	101.	TAXMUA
15.	YOJXOM03	44.	BOWKOO07	73.	LCYSTN25	102.	TERTEP
16.	YOJXOM04	45.	BOWKOO08	74.	LOCJET	103.	UDUVUL
17.	YOJXOM05	46.	CEDYEQ	75.	LOCJET01	104.	VEDCOW
18.	YOJXOM06	47.	CEJTEQ	76.	LOCJET02	105.	VEZLOC
19.	YOJXOM07	48.	CYSCLM11	77.	LOCJET03	106.	VINWUM
20.	YOJXOM08	49.	DIXFAS	78.	LOCJET04	107.	VOPBEH
21.	YOJXOM09	50.	FEDQIP	79.	LOCJET05	108.	WAQFEZ
22.	YOJXOM10	51.	FENJUD	80.	LOCJET06	109.	WEGDES
23.	ADIXOA	52.	GLUTAS02	81.	LOCJET07	110.	WESZUQ
24.	BARPOB	53.	GLUTAS03	82.	LOCJET08	111.	WOGRIT
25.	BEQPUI	54.	GLUTAS04	83.	LOCJET09	112.	WUQZAJ
26.	BOQCUF	55.	GLUTAS05	84.	LOCLOF	113.	XAFVEH
27.	BOQCUF01	56.	GLUTAS06	85.	LOCLOF01	114.	XIJKIK01
28.	BOQCUF02	57.	GOMDAN	86.	NALCYS17	115.	XUHLOC
29.	BOOCUF03	58.	HESTAB	87.	OWADUM	116.	YAJHEW

Energies of interactions. The methods for potential curve calculations were chosen because they are in agreement with the CCSD(T) energies on limit. These methods have similar energy values with energy values obtained by CCSD(T) method, which is considered as golden standard in quantum chemistry (deviation is less than 10%). The single point calculations on potential curves were done with TPSS-D3/aug-cc-pVDZ method for parallel model systems (A, B and C), with TPSS-D3BJ/aug-cc-pVDZ method for model system with normal orientation (D), and with MP2/cc-pVQZ method for model system E (Table S4).

Table S4. Comparison of interaction energy values calculated using different quantum chemical methods with the energy values calculated at CCSD(T)/CBS level

Model system	$\Delta E_{CCSD(T)}$	$\Delta E_{interaction}$
Wibuci system	(kcal/mol)	(kcal/mol)
Α	-0.52	-0.57 ^a
В	-0.72	-0.78 ^a
С	-1.80	-1.81 ^a
D	-0.37	-0.33 ^b
Ε	-2.20	-2.19 ^c

^a TPSS-D3/aug-cc-pVDZ

^b TPSS-D3BJ/aug-cc-pVDZ

^c MP2/cc-pVQZ

Single point calculations were performed for different offsets (r) along three directions (Figure S2).



Figure S2. The parameters that were used for quantum chemical calculations.

For the geometries of the parallel orientation (model systems A to C, Figure 9) the monomer geometries were kept rigid, while the normal distance R was systematically varied to find the R with the strongest interaction. In the model systems D and E the distance *d* between two sulfur atoms was systematically changed. Model system A was moved along direction 1, model system B along direction 2, model system C along direction 3.

The potential-energy curves for different methanethiol dimers (Figure S3-S7) were additionally calculated with TPSS-D3 method and aug-cc-pVDZ basis set for model systems with parallel orientation (A-C), and using the same functional but with Becke-Johnson damping (TPSS-D3BJ/aug-cc-pVDZ) for model system with normal orientation D. Interaction energies for model system E with maximized electrostatic interaction was calculated using MP2 method and cc-pVQZ basis set. The energies were corrected by the basis set superposition error (BSSE) using the Counterpoise method.



Figure S3. Graph of the S^{...}S interaction energy versus height (R) for different offset (r) values for model system A.



Figure S4. Graph of the S^{...}S interaction energy versus height (R) for different offset (r) values for model system B.



Figure S5. Graph of the S^{...}S interaction energy versus height (R) for different offset (r) values for model system C.



Figure S6. Graph of the S^{...}S interaction energy versus S^{...}S distances (d) for model system D.



Figure S7. Graph of the S^{...}S interaction energy versus S^{...}S distances (d) for model system E.

Cartesian (XYZ) coordinates for most stable orientations of studied model systems.

atom	Х	Y	Ζ
Н	-2.09983	0.965885	1.226844
S	-2.126744	0.729198	-0.087747
С	-2.718016	-0.982387	0.019353
Н	-2.013526	-1.611753	0.553037
Н	-3.697465	-1.0344	0.483249
Н	-2.798534	-1.340226	-1.002833
S	2.126757	-0.729202	0.087748
Н	2.099842	-0.96589	-1.226844
С	2.718028	0.982383	-0.019353
Н	2.798546	1.340222	1.002833
Н	3.697325	1.034428	-0.483565
Н	2.013376	1.611824	-0.552733

 Table S5. Cartesian coordinates for model system A

Table S6. Cartesian coordinates for model system B

atom	Х	Y	Ζ
Н	1.700299	0.903612	1.219593
S	1.938082	0.744669	-0.085433
С	2.623444	-0.930988	0.028796
Н	3.524317	-0.949705	0.633198
Н	1.892556	-1.63174	0.418633
Н	2.8791	-1.224133	-0.985158
S	-1.936226	-0.74548	0.073991
Н	-1.706865	-0.883038	-1.234966
С	-2.625765	0.930309	-0.008855
Н	-2.875222	1.206664	1.011339
Н	-1.899051	1.63871	-0.392627
Н	-3.530895	0.956677	-0.606575

atom	Х	Y	Z
Н	-1.880214	0.943565	1.227856
S	-1.870472	0.708419	-0.087251
С	-2.115174	-1.085877	0.018677
Н	-1.297238	-1.566397	0.545276
Н	-3.062001	-1.329019	0.489447
Н	-2.13209	-1.45081	-1.004031
S	1.870485	-0.708421	0.08725
Н	1.880227	-0.943565	-1.227857
С	2.115186	1.085875	-0.018675
Н	2.132102	1.450807	1.004034
Н	3.061857	1.329021	-0.489759
Н	1.297078	1.566437	-0.544968

Table S7. Cartesian coordinates for model system C

Table S8. Cartesian coordinates for model system D

atom	Х	Y	Z
Н	2.030026	-1.963147	-1.068083
S	0.984203	-1.741076	-0.266937
С	0.984203	-3.368676	0.534008
Н	0.811676	-4.163244	-0.184408
Н	1.908076	-3.543242	1.075497
Н	0.162448	-3.357613	1.243933
S	-0.984203	1.741076	-0.266937
Н	-2.030026	1.963147	-1.068083
С	-0.984203	3.368676	0.534008
Н	-0.162448	3.357613	1.243933
Н	-0.811676	4.163244	-0.184408
Н	-1.908076	3.543242	1.075497

atom	Х	Y	Z
Н	0.00000	0.00000	0.00000
S	0.00000	0.00000	1.336
С	1.801832	0.00000	1.545754
Н	2.250023	-0.890683	1.117929
Н	2.249987	0.890849	1.118238
Н	1.982756	0.00000	2.616577
S	0.00000	0.00000	4.936
Н	-0.891877	0.994712	4.936
С	-1.206255	-1.354823	4.936
Н	-0.629317	-2.274898	4.936
Н	-1.825254	-1.333533	4.045151
Н	-1.825486	-1.333327	5.826683

Table S9. Cartesian coordinates for model system E

Quantum Theory of Atoms In Molecules (QTAIM) analysis and NCI index. The electron density for QTAIM analysis¹ was obtained from MP2/aug-cc-pVQZ calculation on previously modeled the most stable dimer geometry. QTAIM analysis on electron density topology was done with MultiWfn program.² Image of electron density contour map with critical points is created with AIMALL program.³ The NCI index and reduced density gradient were calculated with NCIPLOT program.⁴

QTAIM analysis. QTAIM analysis of the model system E wave function has shown the existence of three critical points between monomers (Figure S8). Two of the CP's corresponds to bond critical points (BCP) and one to the ring critical point (RCP).



Figure S8. Electron density contour map for dimer. Large spheres represent atoms: C - gray, S - yellow and H - white. Small spheres represent critical points: BCPs in green and RCP in blue

This point can be further strengthening with Quantum Atoms in Molecule (QTAIM) and NCI index analysis of model system E. QTAIM analysis of the model system E wave function has shown the existence of two bond critical points (BCP) between molecules. The first BCP occurs between two sulfur atoms and the second between sulfur and hydrogen atom (Figure S9). Properties of electron density calculated at these critical points are shown in Table S10. The electron density at the BCP1 is larger than at the BCP2 indicating that sulfur-sulfur interaction is most responsible for the binding in model system E.

Table S10. Properties of electron density calculated at CP's with QTAIM method for model system E.

	$ ho^{a}$	$ abla^2 ho^b$	$\operatorname{Sign}(\lambda_2)^{\mathrm{c}}$	V _c ^d	Gc ^e	H_{c}^{f}
BCP1	0.007761	0.020317	_	-0.003752	0.004416	0.000664
BCP2	0.006572	0.019267	—	-0.003352	0.004084	0.000733
RCP	0.005883	0.019532	+	-0.003140	0.004011	0.000872

^a electron density at CP

^bLaplacian of electron density at CP

° Sign of the second eigenvalue of the electron density Hessian matrix at CP

d electronic potential energy density at CP

^e electronic kinetic energy density at CP

^f total electron energy density at CP

NCI index. To confirm QTAIM analysis results the calculations of reduced density gradient was performed. The reduced density gradient, coming from the density and its first derivative $(s=1/[2(3\pi^2)^{1/3}]|\nabla\rho|/\rho^{4/3})$, is a dimensionless quantity used to describe the deviation from a

homogeneous electron distribution. Regions where the electron density $\rho(r)$ and reduced density gradient *s* are low correspond to regions where non-covalent interactions occur. The plot of the reduced density gradient versus the electron density multiplied by the sign of the second Hessian eigenvalue (*sign* (λ_2) ρ) (Figure S9) indicates two low gradient low density regions. The booth BCP's lies in the negative *sign* (λ_2) ρ part and RCP is in the positive *sign* (λ_2) ρ part.

Figure S9. Plot of the reduced density gradient *s* and *sign* $(\lambda_2)\rho$ for model system E.

On the Figure S10 a two NCI isosurfaces can be distinguished. The first NCI isosurface lies between two sulfur atoms and is disk-shaped and blue in color indicating an attractive and very localized interaction. At the center of this region lies BCP1. The second NCI isosurface lies between sulfur atom and CH₃ group. The interaction is repulsive near the center of the S-S-C-H ring (red region) and weakly attractive in the region between sulfur and hydrogen atoms. The RCP lies in the repulsive and BCP2 in the attractive region.

Figure S10. Plot of NCI isosurfaces for model system E. A continuous color-coding scheme is used; attractive interactions are represented in blue and repulsive interactions in red. Small spheres represent critical points: BCPs -green, RCP – blue.

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